

1-A DC Motor Driver for Servo Driver Applications

TLE 4206-2G





Overview

Features

- Optimized for headlight beam control applications
- · Delivers up to 0.8 A continuous
- Low saturation voltage; typ.1.2 V total @ 25 °C; 0.4 A
- · Output protected against short circuit
- Overtemperature protection with hysteresis
- · Over- and undervoltage lockout
- · No crossover current
- Internal clamp diodes
- · Enhanced power packages
- Range low-voltage detection with hysteresis
- Green Product (RoHS compliant)
- AEC Qualified



PG-DSO-14

Туре	Ordering Code	Package
TLE 4206-2G	on request	PG-DSO-14

Description

The TLE 4206-2G is a protected H-Bridge Driver designed specifically for automotive headlight beam control and industrial servo control applications. The part is built using Infineons bipolar high voltage power technology DOPL.

The standard enhanced power PG-DSO-14 package meets the application requirements and saves PCB-board space and costs.

The servo-loop-parameter pos.- and neg. Hysteresis, pos.- and neg. deadband and angle-amplification are programmable with external resistors. An internal window-comparator controls the input line. In the case of a fault condition, like short circuit to GND, short circuit to supply-voltage, and broken wire, the TLE 4206-2G stops the motor immediately (brake condition).

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Furthermore the built in features like over- and undervoltage-lockout, short-circuit-protection and over-temperature-protection will open a wide range of automotive- and industrial applications.

The TLE 4206-2G is a design-version of the TLE 4206. In the TLE 4206-2G, the current peak blanking Pin is disconnected. A hysteresis is introduced at the lower RANGE threshold. This allows reliable de-activation of the device by pulling the RANGE input to GND also under critical application conditions.

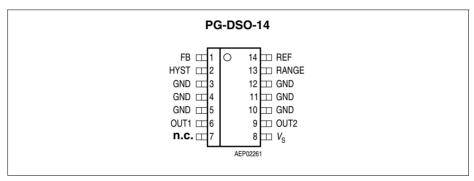


Figure 1 Pin Configuration (top view)

Pin Definitions and Functions

Pin No. PG-DSO-14	Symbol	Function
1	FB	Feedback Input
2	HYST	Hysteresis I/O
3, 4, 5, 10, 11, 12	GND	Ground
6	OUT1	Power Output 1
7	n.c.	Not connected
8	$V_{\mathtt{S}}$	Power Supply Voltage
9	OUT2	Power Output 2
13	RANGE	Range Input
14	REF	Reference Input

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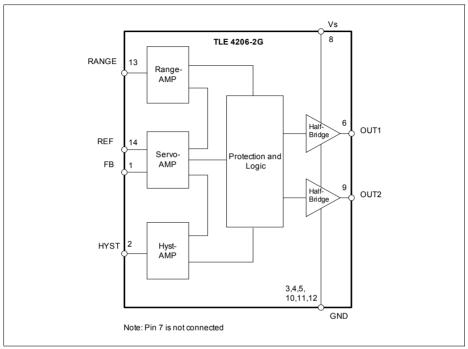


Figure 2 Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		

Voltages

Supply voltage	V_{S}	- 0.3	45	٧	_
Supply voltage	V_{S}	– 1	_	٧	$t < 0.5 \text{ s}; I_{S} > -2 \text{ A}$
Logic input voltages (FB, REF, RANGE, HYST, CPB)	V_{I}	- 0.3	20	V	_

Currents

Output current (OUT1, OUT2)	I_{OUT}	_	_	Α	internally limited
Output current (Diode)	I_{OUT}	– 1	1	Α	_
Input current (FB, REF, RANGE, HYST)	I_{IN}	-2 -6	2 6	mA mA	t < 2 ms; t/T < 0.1

Temperatures

Junction temperature	T_{j}	- 40	150	°C	_
Storage temperature	$T_{\rm stg}$	- 50	150	°C	_

Thermal Resistances

Junction pin (PG-DSO-14)	$R_{ m thj\text{-pin}}$	_	25	K/W	measured to pin 5
Junction ambient (PG-DSO-14)	R_{thjA}	_	65	K/W	_

Note: Maximum ratings are absolute ratings; exceeding any one of these values may cause irreversible damage to the integrated circuit.

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Operating Range

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		
Supply voltage	V_{S}	8	18	٧	After $V_{\rm S}$ rising above $V_{\rm UV\;ON}$
Supply voltage increasing	V_{S}	- 0.3	V_{UVON}	V	Outputs in tristate
Supply voltage decreasing	V_{S}	- 0.3	V_{UVOFF}	V	Outputs in tristate
Output current	I_{OUT1-2}	- 0.8	0.8	Α	_
Input current (FB, REF)	I_{IN}	- 50	500	μΑ	_
Junction temperature	$T_{\rm j}$	- 40	150	°C	_

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Electrical Characteristics

8 V < $V_{\rm S}$ < 18 V; $I_{\rm OUT1\cdot 2}$ = 0 A; - 40 °C < $T_{\rm j}$ < 150 °C (unless otherwise specified)

Parameter	Symbol	Limit Values		Unit	Test Condition	
		min.	typ.	max.		

Current Consumption

Supply current	I_{S}	-	12	20	mA	-
Supply current	$I_{\mathbb{S}}$	_	20	30	mA	$I_{\text{OUT1}} = 0.4 \text{ A}$ $I_{\text{OUT2}} = -0.4 \text{ A}$
Supply current	$I_{\mathbb{S}}$	_	30	50	mA	$I_{\text{OUT1}} = 0.8 \text{ A}$ $I_{\text{OUT2}} = -0.8 \text{ A}$

Over- and Under Voltage Lockout

UV Switch ON voltage	V_{UVON}	_	7.4	8	٧	$V_{ m S}$ increasing
UV Switch OFF voltage	V_{UVOFF}	6.3	6.9	_	٧	$V_{ m S}$ decreasing
UV ON/OFF Hysteresis	V_{UVHY}	_	0.5	_	٧	$V_{ m UVON}$ – $V_{ m UVOFF}$
OV Switch OFF voltage	V_{OVOFF}	_	20.5	23	٧	$V_{ m S}$ increasing
OV Switch ON voltage	V_{OVON}	17.5	20	_	٧	$V_{\rm S}$ decreasing
OV ON/OFF Hysteresis	V_{OVHY}	-	0.5	_	٧	$V_{ m OVOFF}-V_{ m OVON}$

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Electrical Characteristics (cont'd)

8 V < $V_{\rm S}$ < 18 V; $I_{\rm OUT1-2}$ = 0 A; – 40 °C < $T_{\rm j}$ < 150 °C (unless otherwise specified)

Parameter	Symbol	Limit Values		Unit	Test Condition	
		min.	typ.	max.	Ĭ	

Outputs OUT1-2

Saturation Voltages

Source (upper) $I_{\text{OUT}} = -0.2 \text{ A}$	V_{SATU}	_	0.85	1.15	V	<i>T</i> _j = 25 °C
Source (upper) $I_{\text{OUT}} = -0.4 \text{ A}$	V_{SATU}	_	0.90	1.20	V	<i>T</i> _j = 25 °C
Sink (upper) $I_{\text{OUT}} = -0.8 \text{ A}$	V_{SATU}	_	1.10	1.50	٧	<i>T</i> _j = 25 °C
Sink (lower) $I_{\text{OUT}} = 0.2 \text{ A}$	V_{SATL}	_	0.15	0.23	٧	<i>T</i> _j = 25 °C
Sink (lower) $I_{\text{OUT}} = 0.4 \text{ A}$	V_{SATL}	_	0.25	0.40	V	<i>T</i> _j = 25 °C
Sink (lower) $I_{\text{OUT}} = 0.8 \text{ A}$	V_{SATL}	_	0.45	0.75	V	<i>T</i> _j = 25 °C

Total drop	I_{OUT} = 0.2 A	V_{SAT}	_	1.0	1.4	V	$V_{SAT} = V_{SATU} + V_{SATL}$
Total drop	I_{OUT} = 0.4 A	V_{SAT}	_	1.2	1.7	V	$V_{SAT} = V_{SATU} + V_{SATL}$
Total drop	$I_{ m OUT}$ = 0.8 A	V_{SAT}	_	1.6	2.5	V	$V_{SAT} = V_{SATU} + V_{SATL}$

Clamp Diodes

Forward voltage; upper	V_{FU}	_	1	1.5	V	$I_{\rm F} = 0.4 \; {\rm A}$
Upper leakage current	I_{LKU}	_	_	5	mΑ	$I_{\rm F} = 0.4 \; {\rm A}$
Forward voltage; lower	V_{FL}	_	0.9	1.4	V	$I_{\rm F} = 0.4 \; {\rm A}$

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Electrical Characteristics (cont'd)

8 V < $V_{\rm S}$ < 18 V; $I_{\rm OUT1-2}$ = 0 A; - 40 °C < $T_{\rm j}$ < 150 °C (unless otherwise specified)

Parameter	Symbol	Limit Values		Unit	Test Condition	
		min.	typ.	max.	Ĭ	

Input-Interface

Input REF

Quiescent voltage	V_{REFq}	_	200	_	mV	$I_{REF} = 0 \; \mu A$
Input resistance	R_{REF}	_	6	_	kΩ	$0 \text{ V} < V_{\text{REF}} < 0.5 \text{ V}$

Input FB

Quiescent voltage	V_{FBq}	_	200	_	mV	$I_{FB} = 0 \; \mu A$
Input resistance	R_{FB}	_	6	_	kΩ	$0 \text{ V} < V_{\text{FB}} < 0.5 \text{ V}$

Input/Output HYST

Current Amplification $A_{\rm HYST} = I_{\rm HYST} / (I_{\rm REF} - I_{\rm FB})$	A_{HYST}	0.8	0.95	1.1	_	$\begin{array}{l} -20~\mu \mathrm{A} < I_{\mathrm{HYST}} \\ < -10~\mu \mathrm{A}; \\ 10~\mu \mathrm{A} < I_{\mathrm{HYST}} \\ < 20~\mu \mathrm{A}; \\ I_{\mathrm{REF}} = 250~\mu \mathrm{A} \\ V_{\mathrm{HYST}} = V_{\mathrm{S}}/2 \end{array}$
Current Offset	I_{HYSTIO}	-2	0.35	3	μΑ	I_{REF} = I_{FB} = 250 μA V_{HYST} = V_{S} / 2
Threshold voltage High	V_{HYH} / V_{S}	_	52	_	%	-
Deadband voltage High	V_{DBH} / V_{S}	_	50.4	_	%	-
Deadband voltage Low	$V_{ m DBL}/V_{ m S}$	-	49.6	_	%	-
Threshold voltage Low	$V_{ m HYL}/V_{ m S}$	-	48	_	%	-
Hysteresis Window	$V_{ m HYW}/V_{ m S}$	3	4	5	%	$(V_{ m HYH} - V_{ m HYL}) / V_{ m S}$
Deadband Window	V_{DBW} / V_{S}	0.4	8.0	1.2	%	$(V_{ m DBH} - V_{ m DBL}) \! / V_{ m S}$

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Electrical Characteristics (cont'd)

8 V < $V_{\rm S}$ < 18 V; $I_{\rm OUT1-2}$ = 0 A; - 40 °C < $T_{\rm j}$ < 150 °C (unless otherwise specified)

Parameter	Symbol	Limit Values		Unit	Test Condition	
		min.	typ.	max.		

Input RANGE

Input current	I_{RANGE}	- 1	_	1	μΑ	0 V < $V_{\rm RANGE}$ < $V_{\rm S}$
Switch-OFF voltage High	V_{OFFH}	- 25	0	100	mV	refer to $V_{\rm S}$
Switch-OFF voltage Low	V_{OFFL}	310	390	490	mV	$ \begin{array}{cccc} {\rm refer} & {\rm to} & {\rm GND}, \\ V_{\rm RANGE} \ {\rm decreasing} \end{array} $
Switch-ON voltage Low	V_{ONL}	400	500	550	mV	$ \begin{array}{cccc} {\rm refer} & {\rm to} & {\rm GND}, \\ V_{\rm RANGE} & {\rm increasing} \end{array} $
Low-threshold hysteresis	$V_{\sf OFFLHYS}$	50	110	-	mV	see Figure 6

Thermal Shutdown

Thermal shutdown junction temperature	T_{jSD}	150	175	200	°C	_
Thermal switch-on junction temperature	T_{jSO}	120	_	170	°C	_
Temperature hysteresis	ΔT	_	30	_	K	_

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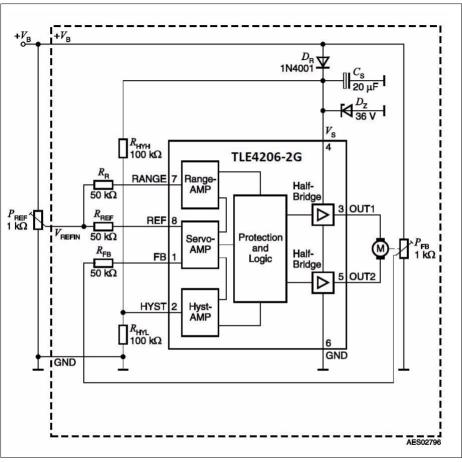


Figure 3 Application Circuit



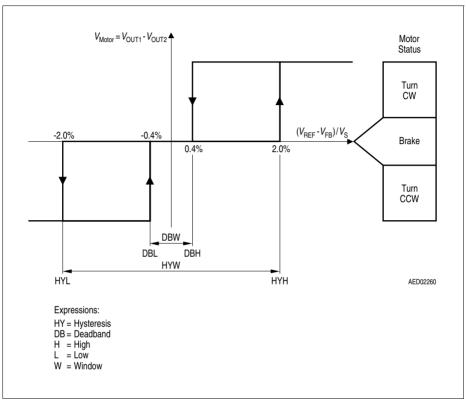


Figure 4 Hysteresis, Phaselag and Deadband-Definitions

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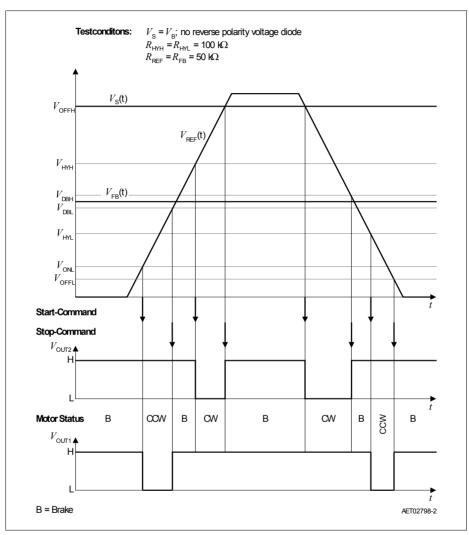


Figure 5 Timing and Phaselag

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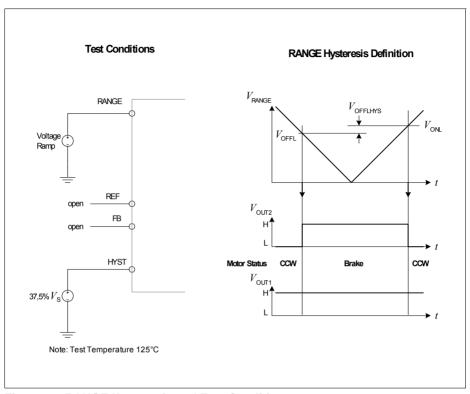


Figure 6 RANGE Hysteresis and Test Conditions

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Package Outlines

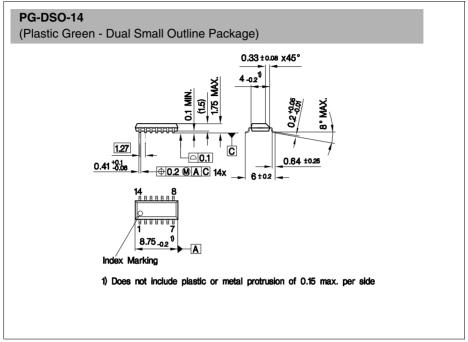


Figure 7 PG-DSO-14 (Plastic/Plastic Green - Dual Small Outline Package)

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

You can find all of our packages, sorts of packing and others in our Infineon Internet Page "Products": http://www.infineon.com/products.

SMD = Surface Mounted Device

Dimensions in mm



Revision History

Version	Date	Changes
Rev. 1.1	2007-08-10	 RoHS-compliant version of the TLE 4206-2 All pages: Infineon logo updated Page 1: "AEC qualified" and "RoHS" logo added, "Green Product (RoHS compliant)" and "AEC qualified" statement added to feature list, package names changed to RoHS compliant versions, package pictures updated, ordering codes removed Page 14: Package names changed to RoHS compliant versions, "Green Product" description added Revision History added Legal Disclaimer added
Rev. 1.2	2008-02-04	 Editorial change: deleted "fully" (The term "fully protected" often leads to misunderstandings as it is unclear with respect to which parameters); page 1 Update Package picture; page1 Update Figure 1; page 2
Rev. 1.3	2017-05-19	Package suffix deleted

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